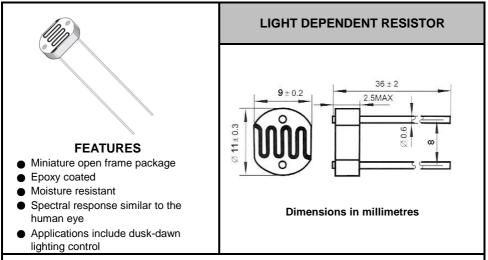


## 晶创和立科技 GL1151 MINIATURE CADMIUM SULPHIDE PHOTOCONDUCTIVE CELL



## SPECIFICATION AND PERFORMANCE

Model	Vmax (VDC)	Pmax (mW)	Ambient temp(℃)	Spectral peak (nm)	Light Resistance at 10Lux (KΩ)	Dark Resistance (MΩ)	Gamm a value at 100- 10Lux	Response Time (ms)	
								Rise Time	Decay time
GL11516	250	250	-30~+70	540	5-10	1	0.6	20	30

# **Measuring Conditions**

#### 1. Light resistance:

Measured at 10 Lux with standard light A (2854K color temperature) and 2hr illumination at 400-600 lux prior to testing. Relative Sensitivity (%) 2. Dark Resistance: Measured 10 senconds after closed 10 lux. 3. Gamma Characteristic: Between 10 lux ande 100 lux and given by y = lg(R10/R100)R10、R100 Cell resistance at 10 lux and 100 lux.

#### The error of $\gamma$ is ± 0.1.

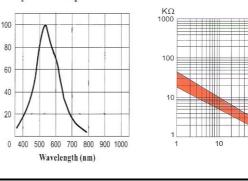
4. Pmax:

Max. power dissipation at ambient temperature of 25 °C.

### 5. Vmax:

Max. voltage in darkness that may be applied to the cell continuously.

### Spectral Response



100lux

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